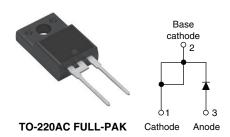


Vishay Semiconductors

### Fast Soft Recovery Rectifier Diode, 20 A



| PRODUCT SUMMARY        |                  |  |  |  |
|------------------------|------------------|--|--|--|
| V <sub>F</sub> at 20 A | < 1.31 V         |  |  |  |
| I <sub>FSM</sub>       | 355 A            |  |  |  |
| $V_{RRM}$              | 1000 V to 1200 V |  |  |  |

#### **FEATURES**

 The fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>) is UL E78996 approved



• Designed and qualified for industrial level

#### **APPLICATIONS**

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions or conducted EMI should be met

#### **DESCRIPTION**

The 20ETF..FPPbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

| MAJOR RATINGS AND CHARACTERISTICS |                              |              |       |  |  |
|-----------------------------------|------------------------------|--------------|-------|--|--|
| SYMBOL                            | CHARACTERISTICS              | VALUES       | UNITS |  |  |
| V <sub>RRM</sub>                  |                              | 1000 to 1200 | V     |  |  |
| I <sub>F(AV)</sub>                | Sinusoidal waveform          | 20           | Α     |  |  |
| I <sub>FSM</sub>                  |                              | 355          |       |  |  |
| t <sub>rr</sub>                   | 1 A, 100 A/µs                | 95           | ns    |  |  |
| V <sub>F</sub>                    | 20 A, T <sub>J</sub> = 25 °C | 1.31         | V     |  |  |
| T <sub>J</sub>                    | Range                        | - 40 to 150  | °C    |  |  |

| VOLTAGE RATINGS |   |  |                                     |  |  |
|-----------------|---|--|-------------------------------------|--|--|
| PART NUMBER     | V <sub>RRM</sub> , MAXIMUM PEAK<br>REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub><br>AT 150 °C<br>mA |  |  |
| 20ETF10FPPbF    | 1000  | 1100   | G                                   |  |  |
| 20ETF12FPPbF    | 1200  | 1300   | O                                   |  |  |

| ABSOLUTE MAXIMUM RATINGS                             |  |  |                  |       |
|--|--|--|------------------|-------|
| PARAMETER  | SYMBOL   | L TEST CONDITIONS VALUES                               |                  | UNITS |
| Maximum average forward current                      | I <sub>F(AV)</sub>                               | T <sub>C</sub> = 97 °C, 180° conduction half sine wave | 20               |       |
| Maximum peak one cycle non-repetitive surge current  |  | 10 ms sine pulse, rated V <sub>RRM</sub> applied       | 300              | А     |
|  | 10 ms sine pulse, no voltage reapplied           | 355  |                  |       |
| Maximum I <sup>2</sup> t for fusing I <sup>2</sup> t | 10 ms sine pulse, rated V <sub>RRM</sub> applied | 450  | A <sup>2</sup> s |       |
|  | 1-1  | 10 ms sine pulse, no voltage reapplied                 | 635              | A-5   |
| Maximum I²√t for fusing                              | I²√t   | t = 0.1 ms to 10 ms, no voltage reapplied              | 6350             | A²√s  |

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

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Revision: 26-Jul-10

| ELECTRICAL SPECIFICATIONS       |                    |                              |   |        |       |
|---------------------------------|--------------------|------------------------------|---|--------|-------|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS              |   | VALUES | UNITS |
| Maximum forward voltage drop    | $V_{FM}$           | 20 A, T <sub>J</sub> = 25 °C |   | 1.31   | V     |
| Forward slope resistance        | r <sub>t</sub>     | T <sub>J</sub> = 150 °C      |   | 11.88  | mΩ    |
| Threshold voltage               | V <sub>F(TO)</sub> |                              |   | 0.93   | V     |
| Maximum vayaya laakaya ayyyant  |                    | T <sub>J</sub> = 25 °C       | V <sub>R</sub> = Rated V <sub>RRM</sub> | 0.1    | A     |
| Maximum reverse leakage current | I <sub>RM</sub>    | T <sub>J</sub> = 150 °C      |   | 6      | mA mA |

| RECOVERY CHARACTERISTICS |                 |                          |        |       |                          |
|--------------------------|-----------------|--------------------------|--------|-------|--------------------------|
| PARAMETER                | SYMBOL          | TEST CONDITIONS          | VALUES | UNITS | · •                      |
| Reverse recovery time    | t <sub>rr</sub> | I <sub>F</sub> at 20 Apk | 400    | ns    | I <sub>FM</sub> +        |
| Reverse recovery current | I <sub>rr</sub> | 25 A/µs<br>25 °C         | 6.1    | Α     | $t_a \mid t_b \mid$      |
| Reverse recovery charge  | Q <sub>rr</sub> |                          | 1.7    | μC    | dir/Q <sub>rr</sub>      |
| Snap factor              | S               | Typical                  | 0.6    |       | I V I <sub>RM(REC)</sub> |

| THERMAL - MECHANICAL SPECIFICATIONS          |         |                                   |                                      |             |                  |
|--|---------|-----------------------------------|--------------------------------------|-------------|------------------|
| PARAMETER                                    |         | SYMBOL                            | TEST CONDITIONS                      | VALUES      | UNITS            |
| Maximum junction and sto temperature range   | orage   | T <sub>J</sub> , T <sub>Stg</sub> |                                      | - 40 to 150 | °C               |
| Maximum thermal resistar junction to case    | nce,    | $R_{thJC}$                        | DC operation                         | 1.5         |                  |
| Maximum thermal resistar junction to ambient | nce,    | R <sub>thJA</sub>                 |                                      | 62          | °C/W             |
| Typical thermal resistance case to heatsink  | €,      | R <sub>thCS</sub>                 | Mounting surface, smooth and greased | 1.5         |                  |
| Approximate weight                           |         |                                   |                                      | 2           | g                |
| Approximate weight                           |         |                                   | 0.07                                 | OZ.         |                  |
| Mounting torque ————                         | minimum |                                   |                                      | 6 (5)       | kgf · cm         |
|  | maximum |                                   |                                      | 12 (10)     | (lbf $\cdot$ in) |
| Marking device                               |         |                                   | Coop at do TO 200AC FULL DAY         | 20ETF10FP   |                  |
|  |         |                                   | Case style TO-220AC FULL-PAK         | 20ETF       | 20ETF12FP        |



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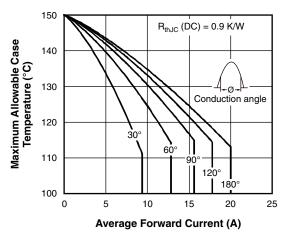


Fig. 1 - Current Rating Characteristics

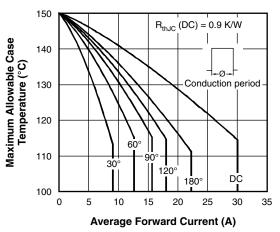


Fig. 2 - Current Rating Characteristics

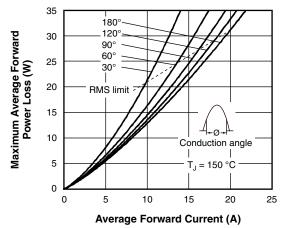


Fig. 3 - Forward Power Loss Characteristics

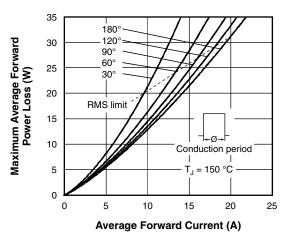
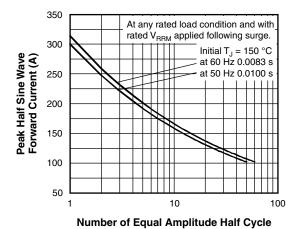


Fig. 4 - Forward Power Loss Characteristics



Current Pulses (N)
Fig. 5 - Maximum Non-Repetitive Surge Current

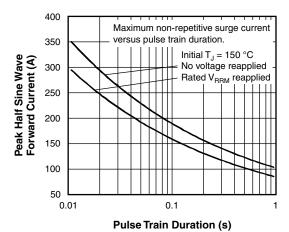


Fig. 6 - Maximum Non-Repetitive Surge Current

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**Fast Soft Recovery** Rectifier Diode, 20 A



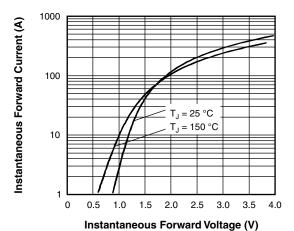
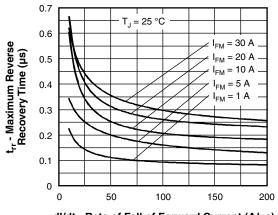


Fig. 7 - Forward Voltage Drop Characteristics



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

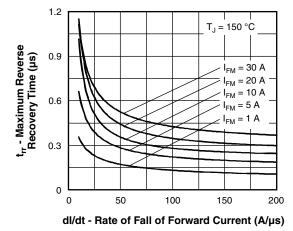
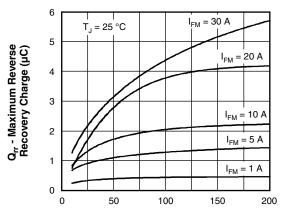
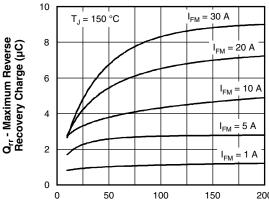


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C



**Fast Soft Recovery** Rectifier Diode, 20 A Vishay Semiconductors

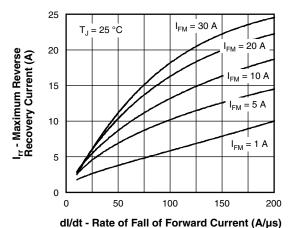
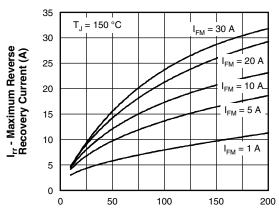


Fig. 12 - Recovery Current Characteristics,  $T_J = 25 \, ^{\circ}\text{C}$ 



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

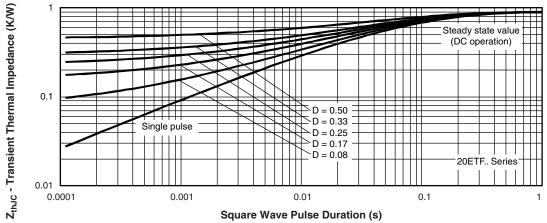


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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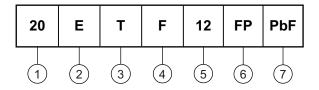


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Revision: 26-Jul-10

#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Current rating (20 = 20 A)
- 2 Circuit configuration:

E = Single diode

- Package:
  - T = TO-220AC
- Type of silicon:

F = Fast soft recovery rectifier

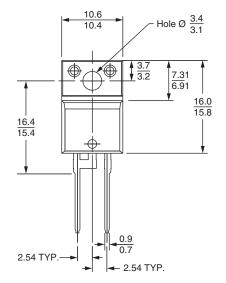
5 - Voltage ratings - 10 = 1000 V 12 = 1200 V

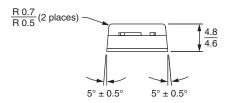
- 6 FULL-PAK
- 7 None = Standard production
  - PbF = Lead (Pb)-free

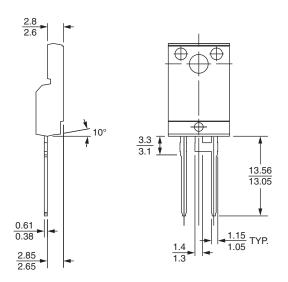
| LINKS TO RELATED DOCUMENTS                 |                          |  |  |  |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95005</u> |                          |  |  |  |
| Part marking information                   | www.vishay.com/doc?95009 |  |  |  |

### Vishay Semiconductors

#### **DIMENSIONS** in millimeters







#### Lead assignments

<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK





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